

**THYRISTOR(Through Hole/Isolated)****SMG16C60F**

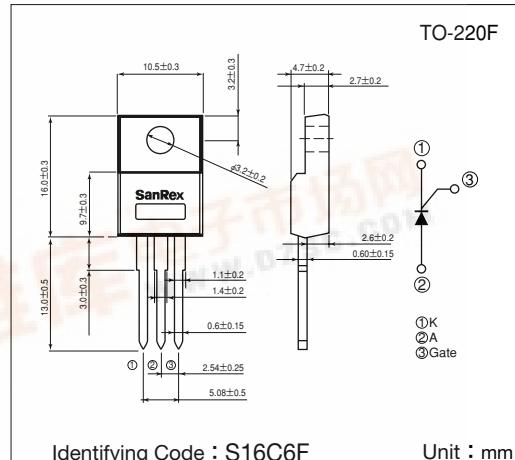
**SanRex** Thyristor **SMG16C60F** is designed for full wave AC control applications. It can be used as an ON/OFF function or for phase control operation.

**Typical Applications**

- Home Appliances : Electric Blankets, Starter for FL, other control applications
- Industrial Use : SMPS, Solenoid for Breakers, Motor Controls, Heater Controls, other control applications

**Features**

- $I_{T(AV)}=16A$
- High Surge Current
- Low Voltage Drop
- Lead-Free Package

**■Maximum Ratings**(T<sub>j</sub>=25°C unless otherwise specified)

Symbol	Item	Reference	Ratings	Unit
V <sub>RRM</sub>	Repetitive Peak Reverse Voltage		600	V
V <sub>RSM</sub>	Non-Repetitive Peak Reverse Voltage		720	V
V <sub>DRM</sub>	Repetitive Peak Off-State Voltage		600	V
I <sub>T(AV)</sub>	Average On-State Current	Single phase, half wave, 180°, conduction, T <sub>c</sub> =58°C	16	A
I <sub>T(RMS)</sub>	R.M.S. On-State Current	Single phase, half wave, 180°, conduction, T <sub>c</sub> =58°C	25.1	A
I <sub>SM</sub>	Surge On-State Current	50Hz/60Hz, ½ cycle Peak value, non-repetitive	240/263	A
I <sup>2</sup> t	I <sup>2</sup> t		288	A <sup>2</sup> S
P <sub>GM</sub>	Peak Gate Power Dissipation		5	W
P <sub>G(AV)</sub>	Average Gate Power Dissipation		0.5	W
I <sub>FGM</sub>	Peak Gate Current		2	A
V <sub>FGM</sub>	Peak Gate Voltage (Forward)		6	V
V <sub>RGM</sub>	Peak Gate Voltage (Reverse)		10	V
V <sub>ISO</sub>	Isolation Breakdown (R.M.S.)	A.C 1minute	1500	V
T <sub>j</sub>	Operating Junction Temperature		-40~+125	°C
T <sub>stg</sub>	Storage Temperature		-40~+150	°C
	Mass		2	g

**■Electrical Characteristics**

Symbol	Item	Reference	Ratings			Unit
			Min.	Typ.	Max.	
I <sub>DRM</sub>	Repetitive Peak Off-State Current	T <sub>j</sub> =125°C, V <sub>D</sub> =V <sub>DRM</sub> ,			2	mA
I <sub>RRM</sub>	Repetitive Peak Reverse Current	T <sub>j</sub> =125°C, V <sub>R</sub> =V <sub>RRM</sub> ,			2	mA
V <sub>TM</sub>	Peak On-State Voltage	I <sub>T</sub> =35A, Inst. measurement			1.5	V
I <sub>GT</sub>	Gate Trigger Current	V <sub>D</sub> =6V, R <sub>L</sub> =10Ω			30	mA
V <sub>GT</sub>	Gate Trigger Voltage				1.4	V
V <sub>GD</sub>	Non-Trigger Gate Voltage	T <sub>j</sub> =125°C, V <sub>D</sub> =½V <sub>DRM</sub> ,	0.2			V
I <sub>H</sub>	Holding Current			15		mA
R <sub>th</sub> (j-c)	Thermal Resistance	Junction to case			3	°C/W

